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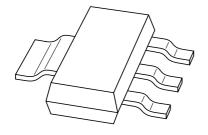
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Team Nexperia

DISCRETE SEMICONDUCTORS

DATA SHEET



BZV90 seriesVoltage regulator diodes

Product data sheet Supersedes data of 1996 Oct 25 1999 May 17



Voltage regulator diodes

BZV90 series

FEATURES

- Total power dissipation: max. 1500 mW
- Tolerance series: approx. ±5%
- Working voltage range: nom. 2.4 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 40 W.

APPLICATIONS

• General regulation functions.

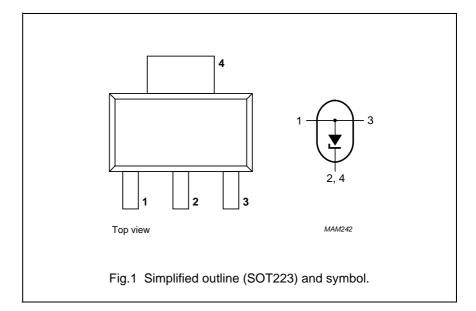
DESCRIPTION

Medium-power voltage regulator diodes in SOT223 plastic SMD packages.

The diodes are available in the normalized E24 approx. $\pm 5\%$ tolerance range. The series consists of 37 types with nominal working voltages from 2.4 to 75 V (BZV90-C2V4 to C75).

PINNING

PIN	DESCRIPTION			
1	anode			
2, 4	cathode			
3	anode			



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _F	continuous forward current		_	400	mA
I _{ZSM}	non-repetitive peak reverse current	t_p = 100 μs; square wave; T_j = 25 °C prior to surge	see Table "Per type"		
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	1500	mW
P _{ZSM}	non-repetitive peak reverse power dissipation	t_p = 100 μs; square wave; T_j = 25 °C prior to surge; see Fig.2	_	40	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

1. Device mounted on an FR4 double-sided copper-clad printed circuit-board; copper area = 2 cm².

ELECTRICAL CHARACTERISTICS

Total series

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA; see Fig.3	I	1.0	V

Voltage regulator diodes

BZV90 series

BZV90- CXXX	VOLT V _Z	KING FAGE (V) Ztest	RESIS r _{di}	RENTIAL STANCE _{if} (Ω) I _{Ztest}	S	IP. COI z (mV/I at I _{Ztest} Figs 4 a	<)	TEST CURRENT I _{Ztest} (mA)	DIODE CAP. $C_{d} (pF)$ at $f = 1$ MHz; at $V_{R} = 0$ V	REVERSE CURRENT at REVERSE VOLTAGE		$ \begin{array}{c cccc} C_d \ (pF) & CURRENT \ at \\ t \ f = 1 \ MHz; & REVERSE & I_{ZSM} \ (A) \\ at \ V_R = 0 \ V & VOLTAGE & at \ t_p = 100 \ \mu s; \end{array} $		at t _p = 100 μs;
										I _R (μ A)	V_{R}	T _{amb} = 25 °C		
	MIN.	MAX.	TYP.	MAX.	MIN.	TYP.	MAX.		MAX.	MAX.	(V)	MAX.		
2V4	2.2	2.6	70	100	-3.5	-1.6	0	5	450	50	1.0	6.0		
2V7	2.5	2.9	75	100	-3.5	-2.0	0	5	450	20	1.0	6.0		
3V0	2.8	3.2	80	95	-3.5	-2.1	0	5	450	10	1.0	6.0		
3V3	3.1	3.5	85	95	-3.5	-2.4	0	5	450	5	1.0	6.0		
3V6	3.4	3.8	85	90	-3.5	-2.4	0	5	450	5	1.0	6.0		
3V9	3.7	4.1	85	90	-3.5	-2.5	0	5	450	3	1.0	6.0		
4V3	4.0	4.6	80	90	-3.5	-2.5	0	5	450	3	1.0	6.0		
4V7	4.4	5.0	50	80	-3.5	-1.4	0.2	5	300	3	2.0	6.0		
5V1	4.8	5.4	40	60	-2.7	-0.8	1.2	5	300	2	2.0	6.0		
5V6	5.2	6.0	15	40	-2.0	1.2	2.5	5	300	1	2.0	6.0		
6V2	5.8	6.6	6	10	0.4	2.3	3.7	5	200	3	4.0	6.0		
6V8	6.4	7.2	6	15	1.2	3.0	4.5	5	200	2	4.0	6.0		
7V5	7.0	7.9	6	15	2.5	4.0	5.3	5	150	1	5.0	4.0		
8V2	7.7	8.7	6	15	3.2	4.6	6.2	5	150	0.7	5.0	4.0		
9V1	8.5	9.6	6	15	3.8	5.5	7.0	5	150	0.5	6.0	3.0		
10	9.4	10.6	8	20	4.5	6.4	8.0	5	90	0.2	7.0	3.0		
11	10.4	11.6	10	20	5.4	7.4	9.0	5	85	0.1	8.0	2.5		
12	11.4	12.7	10	25	6.0	8.4	10.0	5	85	0.1	8.0	2.5		
13	12.4	14.1	10	30	7.0	9.4	11.0	5	80	0.1	8.0	2.5		
15	13.8	15.6	10	30	9.2	11.4	13.0	5	75	0.05	10.5	2.0		
16	15.3	17.1	10	40	10.4	12.4	14.0	5	75	0.05	11.2	1.5		
18	16.8	19.1	10	45	12.4	14.4	16.0	5	70	0.05	12.6	1.5		
20	18.8	21.2	15	55	14.4	16.4	18.0	5	60	0.05	14.0	1.5		

WORKING

DIFFERENTIAL

Voltage regulator diodes

Product data sheet

TEST

DIODE CAP.

REVERSE

NON-REPETITIVE PEAK

TEMP. COEFF.

Voltage regulator diodes

BZV90 series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	lead length max.; note 1	83.3	K/W

5

Note

1. Device mounted on an FR4 double-sided copper-clad printed circuit-board; copper area = 2 cm².

GRAPHICAL DATA

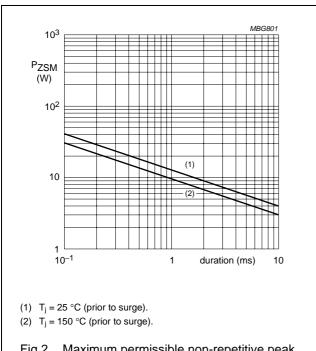


Fig.2 Maximum permissible non-repetitive peak reverse power dissipation versus duration.

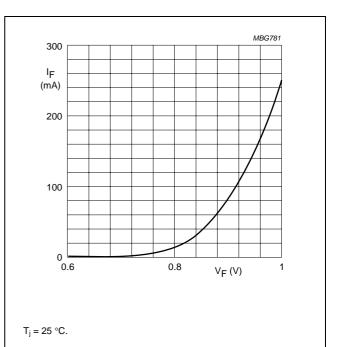
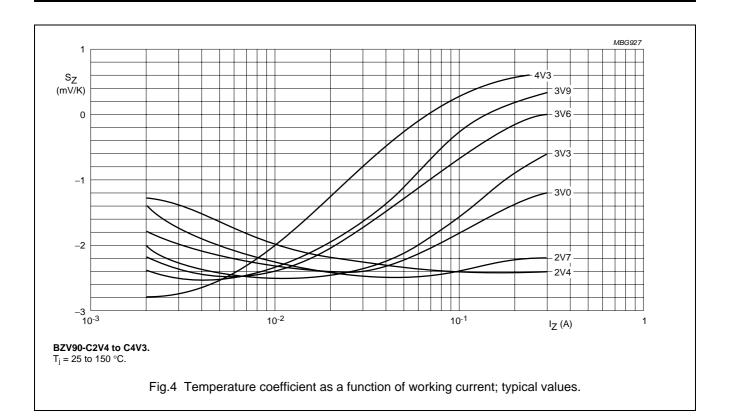


Fig.3 Forward current as a function of forward voltage; typical values.

1999 May 17

Voltage regulator diodes

BZV90 series



MBG924 10 S_Z (mV/K) 10 9V1 5 8V2 7V5 6V8 6V2 5V6 5V1 8 12 16 _{IZ} (mA) 20 **BZV90-C4V7 to C10.** $T_j = 25$ to 150 °C. Fig.5 Temperature coefficient as a function of working current; typical values.

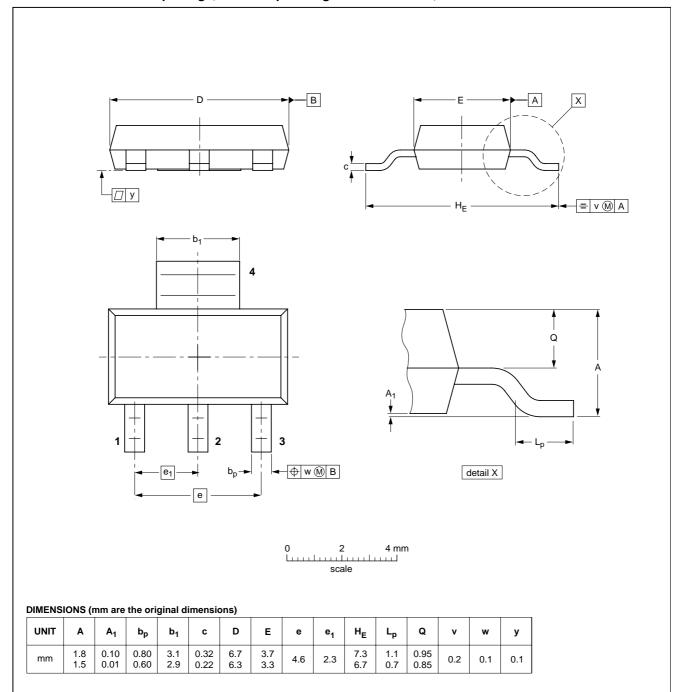
Voltage regulator diodes

BZV90 series

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



EUROPEAN	ISSUE DATE	
PROJECTION	1930E DATE	
	97-02-28 99-09-13	
_		

1999 May 17 7

Voltage regulator diodes

BZV90 series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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Printed in The Netherlands 115002/00/03/pp9 Date of release: 1999 May 17 Document order number: 9397 750 05928



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